NSN 5961-01-250-9193

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View Online at https://aerobasegroup.com/nsn/5961-01-250-9193 **Inclosure Material:** Metal **Overall Length:** 1.250 inches **Overall Height:** 0.295 inches **Overall Width:** 0.700 inches **End Application:** 1440-01-116-9635 **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 18876-11448445 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure:**

Fiig:

No

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Demilitarization: